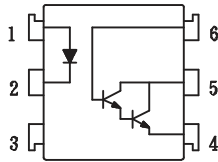


Schematic:



For dimensions and pin-outs, see the last page of this document.

Features:

- High current transfer ratio
(CTR:MIN.500% at $I_F=10\text{mA}$, $V_{CE}=5\text{V}$)
MIN 200% at $I_F=1\text{mA}$, $V_{CE}=1\text{V}$)
- High isolation voltage between input and output
(Viso:5300Vrms).

Ordering:

Suffix to Standard Part Number

- V = VDE Compliant
- G = 10mm Lead Spread
- S = Surface Mount Lead-form
- T = Tape & Reel

Superior OPTO Part Number:

OPTO621

Absolute Maximum Ratings

($T_a=25^\circ\text{C}$)

Parameter	Symbol	Rating	Unit	
Input	Forward current	I_F	50	mA
	Peak forward current	I_{FM}	1	A
	Reverse voltage	V_R	6	V
	Power dissipation	P_D	70	mW
Output	Collector-emitter voltage	V_{CEO}	30	V
	Collector-base voltage	V_{CBO}	30	V
	Emitter-base voltage	V_{EBO}	6	V
	Collector current	I_C	150	mA
	Collector power dissipation	P_C	200	mW
Total power dissipation	P_{tot}	200	mW	
Isolation voltage 1 minute	V_{iso}	5300	Vrms	
Operating temperature	T_{opr}	-30 to +100	$^\circ\text{C}$	
Storage temperature	T_{stg}	-55 to +125	$^\circ\text{C}$	
Soldering temperature 10 second	T_{sol}	260	$^\circ\text{C}$	

Electrical Characteristics

($T_a=25^\circ$)

Parameter	Symbol	Conditions	MIN.	TYP.	MAX.	Unit	
Input	Forward voltage	V_F	$I_F=10\text{mA}$	—	1.2	1.4	V
	Peak forward voltage	V_{FM}	$I_{FM}=0.5\text{A}$	—	—	3.5	V
	Reverse current	I_R	$V_R=4\text{V}$	—	—	10	μA
	Terminal capacitance	C_t	$V=0$, $f=1\text{kHz}$	—	30	—	pF
Output	Collector dark current	I_{CE0}	$V_{CE}=10\text{V}$, $I_F=0$	—	—	0.1	μA
Transfer characteristics	Current transfer ratio	CTR	$I_F=10/1\text{mA}$, $V_{CE}=5/1\text{V}$	500/200	—	—	%
	Collector-emitter saturation voltage	$V_{CE(sat)}$	$I_F=1\text{mA}$, $I_C=2\text{mA}$	—	—	1.0	V
	Isolation resistance	Riso	DC500V	5×10^{10}	—	—	ohm
	Floating capacitance	C_f	$V=0$, $f=1\text{MHz}$	—	0.6	1.0	pF
	Cut-off frequency	f_c	$V_{CC}=5\text{V}$, $I_C=2\text{mA}$, $R_L=100\text{ohm}$	—	7	—	kHz
	Response time (Rise)	t_r	$V_{CE}=10\text{V}$, $I_C=50\text{mA}$, $R_L=100\text{ohm}$	—	5	40	μs
Response time (Fall)	t_f	—		60	100	μs	

Fig.1 Forward Current vs. Ambient Temperature

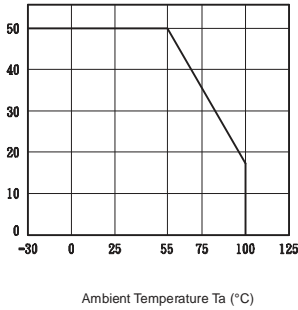


Fig.2 Collector Power Dissipation vs. Ambient Temperature

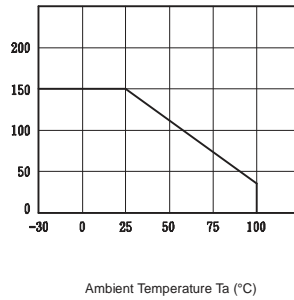


Fig.3 Peak Forward Current vs. Duty Ratio

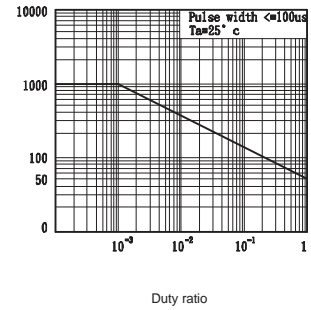


Fig.4 Forward Current vs. Forward Voltage

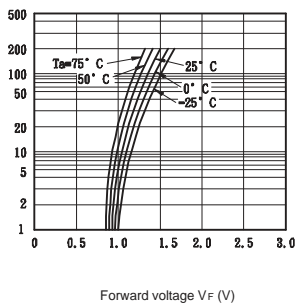


Fig.5 Current Transfer Ratio vs. Forward Current

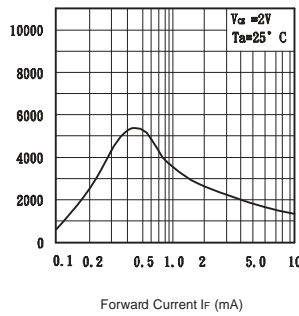


Fig.6 Collector Current vs. Collector-emitter Voltage

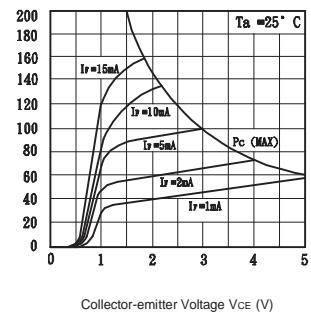


Fig.7 Relative Current Transfer Ratio vs. Ambient Temperature

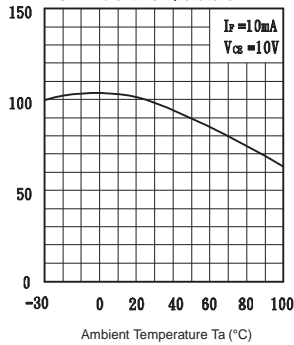


Fig.8 Collector-emitter Saturation Voltage vs. Ambient Temperature

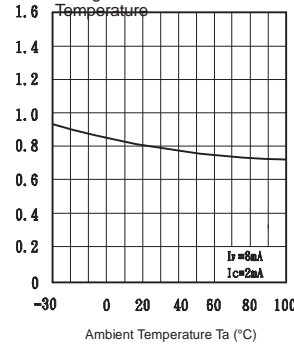


Fig.9 Collector Dark Current vs. Ambient Temperature

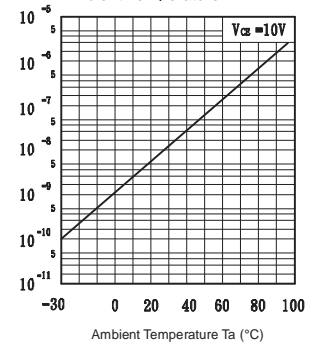


Fig.10 Response Time vs. Load Resistance

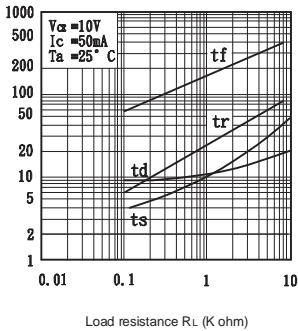


Fig.11 Collector-emitter Saturation Voltage vs. Forward current

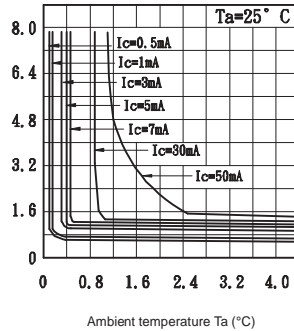


Fig.4 : 6-pin DIP type

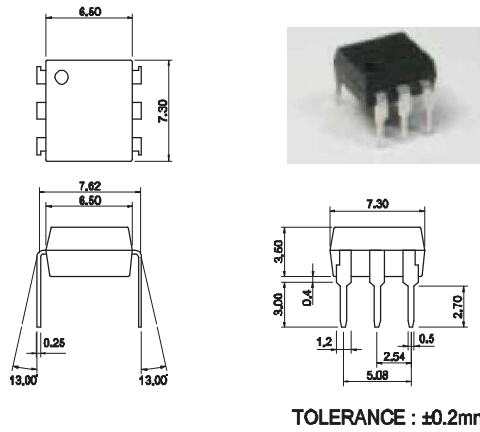


Fig.5 : 6-pin SMD type

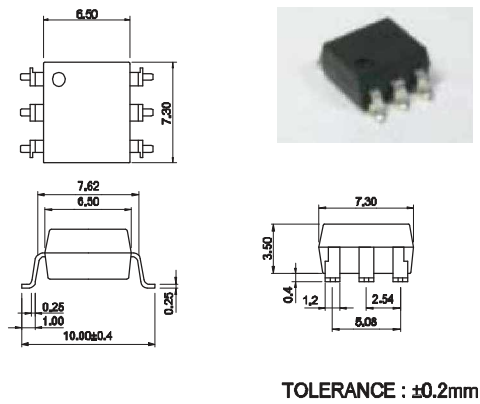


Fig.6 : 6-pin G type

